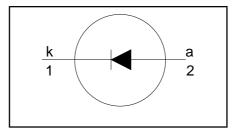
BYV29X-600

### **FEATURES**

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

### **SYMBOL**



#### **QUICK REFERENCE DATA**

$$V_R = 600V$$
 $V_F \le 1.03 V$ 
 $I_{F(peak)} = 7 A$ 
 $t_{rr} \le 60 \text{ ns}$ 

### **GENERAL DESCRIPTION**

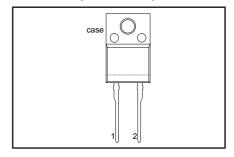
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV29X-600 is supplied in the conventional leaded SOD113 (SOT186a) package.

### **PINNING**

| DESCRIPTION |  |  |
|-------------|--|--|
| _           |  |  |
|             |  |  |
|             |  |  |
|             |  |  |
|             |  |  |

# SOD113 (SOT186a)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

| SYMBOL             | PARAMETER                            | CONDITIONS   | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|--|------|------|------|
| $V_{RRM}$          | Peak repetitive reverse voltage      |  | -    | 600  | V    |
| $V_{RWM}$          | Crest working reverse voltage        |  | -    | 600  | V    |
| $V_R$              | Continuous reverse voltage           |  | -    | 600  | V    |
| I <sub>F(AV)</sub> | Average forward current <sup>1</sup> | square wave; $\delta = 0.5$ ;<br>$T_{mb} \le 100 ^{\circ}\text{C}$ | -    | 9    | Α    |
| I <sub>FRM</sub>   | Repetitive peak forward current      | $t = 25 \mu s; \delta = 0.5;$<br>$T_{mb} \le 100 \text{ °C}$       | -    | 18   | Α    |
| I <sub>FSM</sub>   | Non-repetitive peak forward          | t = 10 ms  | _    | 70   | Α    |
| -F-SIVI            | current.                             | t = 8.3 ms<br>sinusoidal; with reapplied                           | -    | 77   | A    |
|                    |                                      | $V_{RRM(max)}$   |      |      |      |
| T <sub>stg</sub>   | Storage temperature                  |  | -40  | 150  | °C   |
| T <sub>i</sub>     | Operating junction temperature       |  | -    | 150  | °C   |

### THERMAL RESISTANCES

| SYMBOL               | PARAMETER                                | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |
|----------------------|--|--------------|------|------|------|------|
| R <sub>th j-hs</sub> | Thermal resistance junction to heat sink |              | -    | -    | 5.5  | K/W  |
| R <sub>th j-a</sub>  |  | in free air. | 1    | 60   | 1    | K/W  |

<sup>1</sup> Neglecting switching and reverse current losses.

BYV29X-600

# **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs}$  = 25 °C unless otherwise specified

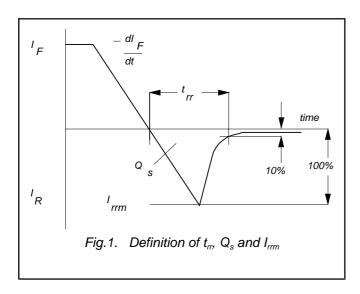
| SYMBOL            | PARAMETER   | CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|-------------------|---|---|------|------|------|------|
| V <sub>isol</sub> | R.M.S. isolation voltage from both terminals to external heatsink | f = 50-60 Hz; sinusoidal<br>waveform;<br>R.H. ≤ 65%; clean and dustfree | -    |      | 2500 | V    |
| C <sub>isol</sub> | Capacitance from both terminals to external heatsink              | f = 1 MHz   | -    | 10   | -    | pF   |

# **ELECTRICAL CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

| SYMBOL           | PARAMETER                     | CONDITIONS   | MIN. | TYP. | MAX. | UNIT     |
|------------------|-------------------------------|--|------|------|------|----------|
| $V_{F}$          | Forward voltage               | $I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$                 | -    | 0.90 | 1.03 | V        |
| ·                |                               | $I_F = 8 \text{ A}$  | -    | 1.05 | 1.25 | V        |
|                  |                               | $I_{\rm F} = 20  \text{A}$                                     | -    | 1.30 | 1.45 | V        |
| I <sub>R</sub>   | Reverse current               | $V_R = V_{RRM}$  | -    | 2.0  | 50   | μΑ       |
|                  |                               | $V_{\rm p} = V_{\rm ppm}$ ; $T_{\rm i} = 100  {\rm ^{\circ}C}$ | -    | 0.1  | 0.35 | μA<br>mA |
| $Q_s$            | Reverse recovery charge       | $II_F = 2 \text{ A to } V_R \ge 30 \text{ V};$                 | -    | 40   | 70   | nC       |
|                  |                               | $dI_F/dt = 20 \text{ A}/\mu\text{s}$                           |      |      |      |          |
| t <sub>rr</sub>  | Reverse recovery time         | $I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$                  | -    | 50   | 60   | ns       |
|                  |                               | $dI_F/dt = 100 A/\mu s$  |      |      |      |          |
| I <sub>rrm</sub> | Peak reverse recovery current | $I_{\rm F} = 10 \text{ A to V}_{\rm R} \ge 30 \text{ V};$      | -    | 3.0  | 5.5  | Α        |
|                  | 1                             | $dI_{F}/dt = 50 A/\mu s; T_{i} = 100^{\circ}C$                 |      |      |      |          |
| $V_{fr}$         | Forward recovery voltage      | $I_F = 10 \text{ A}$ ; $dI_F/dt = 10 \text{ A/}\mu\text{s}$    | -    | 3.2  | -    | V        |

BYV29X-600



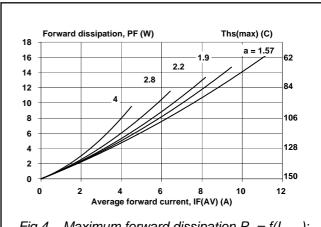
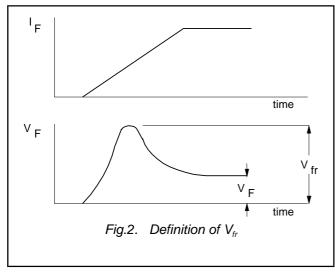
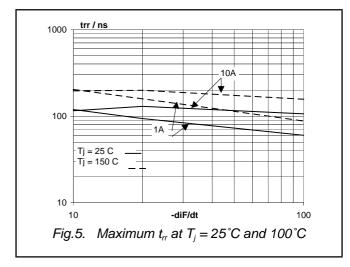
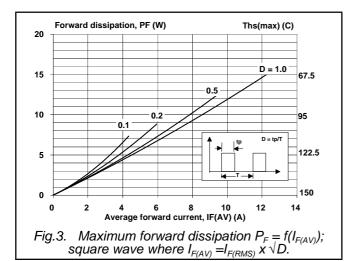
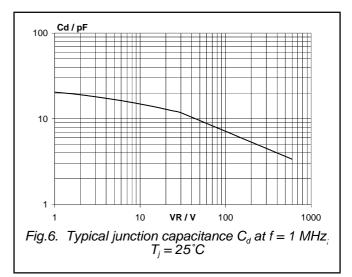


Fig.4. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

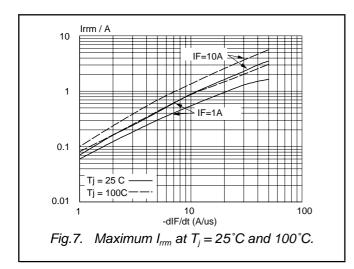


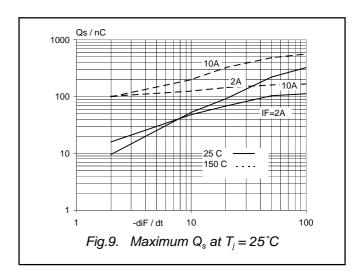






BYV29X-600





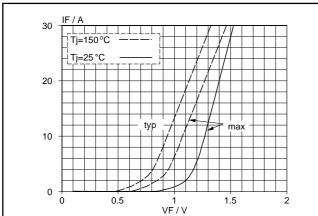
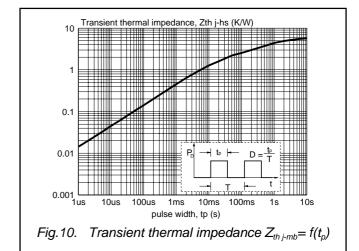
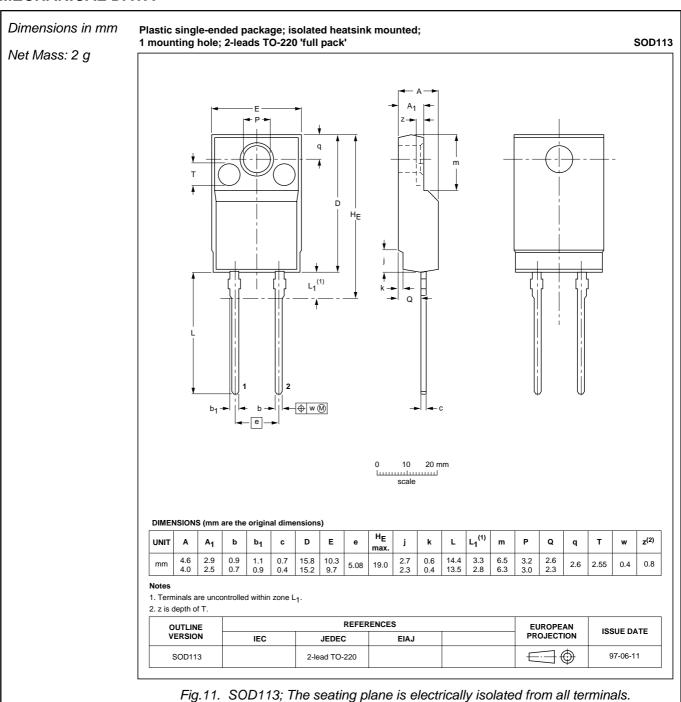


Fig.8. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 



BYV29X-600

### **MECHANICAL DATA**



#### **Notes**

- Refer to mounting instructions for F-pack envelopes.
   Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Rectifier diodes ultrafast

BYV29X-600

#### **DEFINITIONS**

| Data sheet status         |   |
|---------------------------|---|
| Objective specification   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification     | This data sheet contains final product specifications.                                |
| Limiting values           |   |

## Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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